











SN54LVC32A, SN74LVC32A

SCAS286R - JANUARY 1993-REVISED OCTOBER 2016

SNx4LVC32A Quadruple 2-Input Positive-OR Gates

Features

- Operate From 1.65 V to 3.6 V
- Specified From -40°C to +85°C, -40°C to +125°C, and -55°C to +125°C
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 3.8 ns at 3.3 V
- Typical V_{OLP} (Output Ground Bounce) $< 0.8 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V_{OHV} (Output V_{OH} Undershoot) $> 2 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- On Products Compliant to MIL-PRF-38535, All Parameters Are Tested Unless Otherwise Noted. On All Other Products, Production Processing Does Not Necessarily Include Testing of All Parameters.
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model
 - 200-V Machine Model
 - 1000-V Charged-Device Model

Applications

- **AV Receivers**
- Audio Docks: Portable
- Blu-ray Players and Home Theater
- MP3 Players or Recorders
- Personal Digital Assistant (PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid State Drives (SSDs): Client and Enterprise
- TVs: LCD, Digital, and High-Definition (HDTV)
- Tablets: Enterprise
- Video Analytics: Server
- Wireless Headsets, Keyboards, and Mice

3 Description

The SN54LVC32A quadruple 2-input positive-OR gate is designed for 2.7-V to 3.6-V V_{CC} operation, and the SN74LVC32A quadruple 2-input positive-OR gate is designed for 1.65-V to 3.6-V V_{CC} operation.

The SNx4LVC32A devices perform the Boolean function Y = A + B or $Y = \overline{A} \bullet \overline{B}$ in positive logic.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74LVC32AD	SOIC (14)	8.65 mm × 3.91 mm
SN74LVC32ADB	SSOP (14)	6.20 mm × 5.30 mm
SN74LVC32ANS	SO (14)	10.30 mm × 5.30 mm
SN74LVC32APW	TSSOP (14)	5.00 mm × 4.40 mm
SN74LVC32ARGY	VQFN (14)	3.50 mm × 3.50 mm
SN54LVC32AJ	CDIP (14)	19.56 mm × 6.67 mm
SN54LVC32AW	CFP (14)	9.21 mm × 5.97 mm
SN54LVC32AFK	LCCC (20)	8.89 mm × 8.89 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

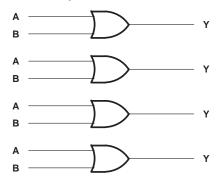




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4 Revision History

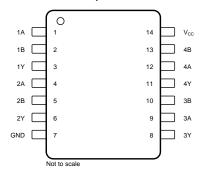
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

_	Added Junction temperature, T _J in <i>Absolute Maximum Ratings</i> Deleted open-drain from <i>Application Information</i> Added <i>Receiving Notification of Documentation Updates</i> section and <i>Community Resources</i> section Changes from Revision P (April 2005) to Revision Q Pag Added <i>Applications</i> , <i>Device Information</i> table, <i>Pin Functions</i> table, <i>ESD Ratings</i> table, <i>Thermal Information</i> table, <i>Typical Characteristics</i> , <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and	
•	Added CDIP (14), CFP (14), and LCCC (20) packages to Device Information table	1
•	Added Junction temperature, T _J in <i>Absolute Maximum Ratings</i>	4
•	Deleted open-drain from Application Information	10
•	Added Receiving Notification of Documentation Updates section and Community Resources section	12
C	Changes from Revision P (April 2005) to Revision Q	Page
C		Page
_	Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation	
_	Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and	1

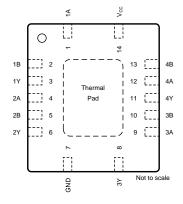


5 Pin Configuration and Functions

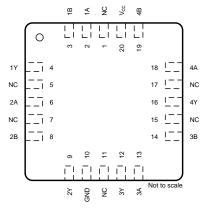
SN54LVC32A J or W Package SN74LVC32A D, DB, NS, or PW Package 14-Pin CDIP, CFP, SOIC, SSOP, SO, TSSOP Top View



SN74LVC32A RGY Package 14-Pin VQFN With Thermal Pad Top View



SN54LVC32A FK Package 20-Pin LCCC Top View



NC - No internal connection

Pin Functions

		PIN				
NAME	SN74LVC32A		SN54LVC32A		TYPE	DESCRIPTION
INAIVIE	D, DB, NS, PW	RGY	J, W	FK		
1A	1	1	1	2	I	Gate 1 input
1B	2	2	2	3	I	Gate 1 input
1Y	3	3	3	4	0	Gate 1 output
2A	4	4	4	6	I	Gate 2 input
2B	5	5	5	8	I	Gate 2 input
2Y	6	6	6	9	0	Gate 2 output
GND	7	7	7	10	_	Ground Pin
3Y	8	8	8	12	0	Gate 3 output
3A	9	9	9	13	I	Gate 3 input
3B	10	10	10	14	I	Gate 3 input
4Y	11	11	11	16	0	Gate 4 output
4A	12	12	12	18	I	Gate 4 input
4B	13	13	13	19	I	Gate 4 input
V _{CC}	14	14	14	20		Power Pin
NC	_	_	_	1, 5, 7, 11, 15, 17	_	No Connection

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		-0.5	6.5	V
VI	Input voltage ⁽²⁾		-0.5	6.5	V
Vo	Output voltage ⁽²⁾⁽³⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
P _{tot}	Power dissipation	$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}^{(4)(5)}$		500	mW
T_J	Junction temperature			150	°C
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
V	Floatroatatio dia abarra	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	2000	V
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101 (2)	1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The value of V_{CC} is provided in the Recommended Operating Conditions tables.

⁽⁴⁾ For the D package: above 70°C, the value of Ptot derates linearly with 8 mW/K.

⁽⁵⁾ For the DB, DGV, NS, and PW packages: above 60°C, the value of P_{tot} derates linearly with 5.5 mW/K.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.3 Recommended Operating Conditions, SN54LVC32A

over operating free-air temperature range (unless otherwise noted)(1)

			SN54LV0	SN54LVC32A	
			−55 to +125°C		UNIT
			MIN	MAX	
\/	Cumply voltage	Operating	2	3.6	\/
V _{CC}	Supply voltage	Data retention only	1.5		V
V _{IH}	High-level input voltage	V _{CC} = 2.7 V to 3.6 V	2		V
V _{IL}	Low-level input voltage	V _{CC} = 2.7 V to 3.6 V		0.8	V
VI	Input voltage	•	0	5.5	V
Vo	Output voltage		0	V _{CC}	V
	High lavel autout august	V _{CC} = 2.7 V		-12	A
I _{OH}	High-level output current	V _{CC} = 3 V		-24	mA
	Law law law day day and a summer law	V _{CC} = 2.7 V		12	1
l _{OL}	Low-level output current	V _{CC} = 3 V		24	mA
Δt/Δν	Input transition rise and fall rate	·		7	ns/V

All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See *Implications of Slow or Floating CMOS Inputs*, SCBA004.

6.4 Recommended Operating Conditions, SN74LVC32A

over operating free-air temperature range (unless otherwise noted)(1)

			SN74LVC32A						
			T _A = 25	T _A = 25°C -40 to +85°C -4		-40 to +125°C		UNIT	
			MIN	MAX	MIN	MAX	MIN	MAX	
.,	Complement	Operating	1.65	3.6	1.65	3.6	1.65	3.6	V
V _{CC}	Supply voltage	Data retention only	1.5		1.5		1.5		V
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	0.65 × V _{CC}		0.65 × V _{CC}		0.65 × V _{CC}		
V _{IH}	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		1.7		1.7		V
	voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		2		2		
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	0.3	5 × V _{CC}	0.	35 × V _{CC}		0.35 × V _{CC}	
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7		0.7		0.7	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		0.8		0.8	
V_{I}	Input voltage		0	5.5	0	5.5	0	5.5	V
Vo	Output voltage		0	V_{CC}	0	V_{CC}	0	V_{CC}	V
		$V_{CC} = 1.65 \text{ V}$		-4		-4		-4	
	High-level output	$V_{CC} = 2.3 \text{ V}$		-8		-8		-8	mA
I _{OH}	current	$V_{CC} = 2.7 \text{ V}$		-12		-12		-12	ША
		$V_{CC} = 3 V$		-24		-24		-24	
		$V_{CC} = 1.65 \text{ V}$		4		4		4	
	Low-level output	$V_{CC} = 2.3 \text{ V}$		8		8		8	mA
I _{OL}	current	$V_{CC} = 2.7 \text{ V}$		12		12		12	
		$V_{CC} = 3 V$		24		24		24	
Δt/Δν	Input transition rise a	and fall rate		7		7		7	ns/V

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See *Implications of Slow or Floating* CMOS Inputs, SCBA004.

Product Folder Links: SN54LVC32A SN74LVC32A



6.5 Thermal Information

			SNx4LVC32A						
THERMAL METRIC ⁽¹⁾		D	DB	NS	PW	RGY	UNIT		
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS			
$R_{\theta JA}$	Junction-to-ambient thermal resistance	86	96	76	113	47	°C/W		

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.6 Electrical Characteristics, SN54LVC32A

over operating free-air temperature range (unless otherwise noted)

			SN54LVC32A	UNIT
PARAMETER	TEST CONDITIONS	V _{cc}	−55 to +125°C	
			MIN MAX	
	$I_{OH} = -100 \mu A$	2.7 V to 3.6 V	V _{CC} - 0.2	
V	1 42 mA	2.7 V	2.2	V
V _{OH}	$I_{OH} = -12 \text{ mA}$	3 V	2.4	V
	$I_{OH} = -24 \text{ mA}$	3 V	2.2	
	I _{OL} = 100 μA	2.7 V to 3.6 V	0.2	
V _{OL}	I _{OL} = 12 mA	2.7 V	0.4	V
	I _{OL} = 24 mA	3 V	0.55	
I _I	V _I = 5.5 V or GND	3.6 V	±5	μΑ
I _{CC}	$V_{I} = V_{CC}$ or GND, $I_{O} = 0$	3.6 V	10	μΑ
ΔI_{CC}	One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND	2.7 V to 3.6 V	500	μA

6.7 Electrical Characteristics, SN74LVC32A

over operating free-air temperature range (unless otherwise noted)

						SN74LVC32A			
PARAMETER	TEST CONDITIONS	V _{CC}	T _A = 25°C		-40 to +85°C	-40 to +125°C		UNIT	
			MIN	TYP	MAX	MIN MAX	MIN N	IAX	
	I _{OH} = -100 μA	1.65 V to 3.6 V	V _{CC} - 0.2			V _{CC} - 0.2	V _{CC} - 0.3		
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.29			1.2	1.05		
V _{OH}	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9			1.7	1.55		V
	1 10 m A	2.7 V	2.2			2.2	2.05		
	$I_{OH} = -12 \text{ mA}$	3 V	2.4			2.4	2.25		
	$I_{OH} = -24 \text{ mA}$	3 V	2.3			2.2	2		
	I _{OL} = 100 μA	1.65 V to 3.6 V			0.1	0.2		0.3	
	$I_{OL} = 4 \text{ mA}$	1.65 V			0.24	0.45		0.6	
V _{OL}	$I_{OL} = 8 \text{ mA}$	2.3 V			0.3	0.7	().85	V
	I _{OL} = 12 mA	2.7 V			0.4	0.4		0.6	
	I _{OL} = 24 mA	3 V			0.55	0.55		8.0	
I _I	V _I = 5.5 V or GND	3.6 V			±1	±5		+ 20	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V			1	10		40	μΑ
Δl _{CC}	One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND	2.7 V to 3.6 V			500	500	5	000	μΑ
C _i	$V_I = V_{CC}$ or GND	3.3 V		5		_			pF

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6.8 Switching Characteristics, SN54LVC32A

over operating free-air temperature range (unless otherwise noted) (see Figure 2)

				SN54LVC	32A	
PARAMETER	FROM TO (INPUT) (OUTPUT		V _{cc}	-55 to +12	-55 to +125°C	
	(1141 01)	(0011 01)		MIN	MAX	
	A == D	V	2.7 V		4.4	
τ _{pd}	A or B	Y	3.3 V ± 0.3 V	1	3.8	ns

6.9 Switching Characteristics, SN74LVC32A

over operating free-air temperature range (unless otherwise noted) (see Figure 2)

		TO (OUTPUT)		SN74LVC32A							
PARAMETER	FROM (INPUT)		V _{CC}	T _A = 25°C			-40 to	+85°C	-40 to +125°C		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
			1.8 V ± 0.15 V	1	4.2	8.2	1	8.7	1	10.2	
	A == D	_	2.5 V ± 0.2 V	1	2.6	4.9	1	5.4	1	6.9	
t _{pd}	A or B	Y	2.7 V	1	3	4.2	1	4.4	1	5.5	ns
			3.3 V ± 0.3 V	1	2.5	3.6	1	3.8	1	5	
t _{sk(o)}			3.3 V ± 0.3 V					1		1.5	ns

6.10 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT
			1.8 V	7.5	
C_{pd}	Power dissipation capacitance per gate	f = 10 MHz	2.5 V	10.6	pF
			3.3 V	12.5	

6.11 Typical Characteristics

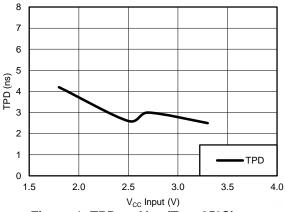
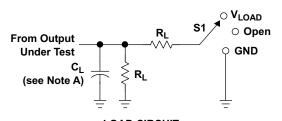


Figure 1. TPD vs V_{CC} ($T_A = 25^{\circ}C$)



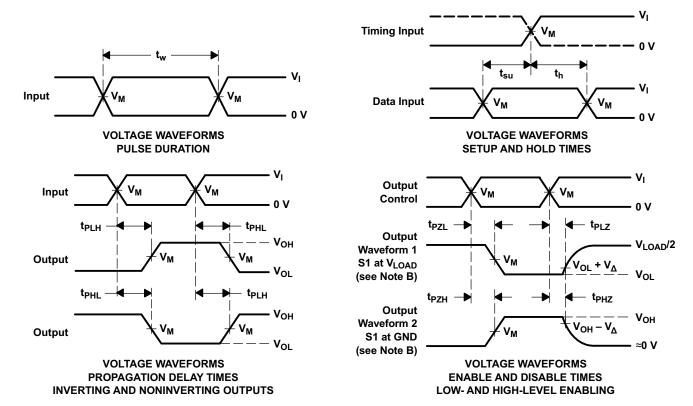
7 Parameter Measurement Information



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

LUAD	CIRCUII	

.,	INI	PUTS	.,			_	.,
V _{CC}	V _{CC} V _I		V _M	V _{LOAD}	CL	R _L	V _A
1.8 V ± 0.15 V	V _{CC}	≤2 ns	V _{CC} /2	2 × V _{CC}	30 pF	1 kΩ	0.15 V
2.5 V ± 0.2 V	V _{CC}	≤2 ns	V _{CC} /2	2 × V _{CC}	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V ± 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms



8 Detailed Description

8.1 Overview

The SN54LVC32A quadruple 2-input positive-OR gate is designed for 2-V to 3.6-V V_{CC} operation, and the SN74LVC32A quadruple 2-input positive-OR gate is designed for 1.65-V to 3.6-V V_{CC} operation.

The SNx4LVC32A devices perform the Boolean function Y = A + B or $Y = \overline{A \bullet B}$ in positive logic.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as down-translators in a mixed 3.3-V/5-V system environment.

8.2 Functional Block Diagram





8.3 Feature Description

- Wide operating voltage range
 - Operates from 1.65 V to 3.6 V
- Allows up or down voltage translation
 - Inputs accept voltages to 5.5 V

8.4 Device Functional Modes

Table 1 lists the functional modes of SNx4LVC32A.

Table 1. Function Table (Each Gate)

	-	-
INP	UTS	OUTPUT
Α	В	Y
Н	Х	Н
X	Н	Н
L	L	L

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9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

SN74LVC32A device is a high-drive, CMOS device that can be used for a multitude of buffer-type functions. It can produce 24 mA of drive current at 3 V. Therefore, this device is ideal for driving multiple inputs and for high-speed applications up to 100 MHz. The inputs and outputs are 5.5-V tolerant allowing the device to translate down to V_{CC} .

9.2 Typical Application

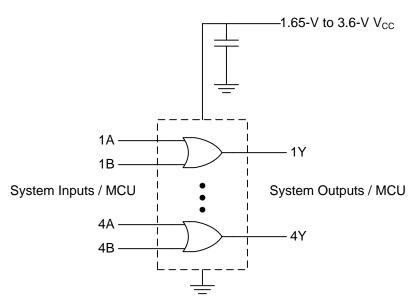


Figure 3. Typical OR Gate Application and Supply Voltage

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads; therefore, routing and load conditions should be considered to prevent ringing.

9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - Rise time and fall time specs: See (Δt/ΔV) in the Recommended Operating Conditions, SN74LVC32A table.
 - Specified high and low levels: See (V_{IH} and V_{IL}) in the Recommended Operating Conditions, SN74LVC32A table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}.
- 2. Recommended Output Conditions
 - Load currents should not exceed 25 mA per output and 50 mA total for the part.
 - Outputs should not be pulled above 5.5 V.



Typical Application (continued)

9.2.3 Application Curve

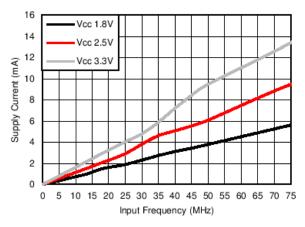


Figure 4. Supply Current vs Input Frequency

10 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions, SN74LVC32A* table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μF is recommended; if there are multiple V_{CC} pins, then 0.01 μF or 0.022 μF is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μF and a 1 μF are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

11 Layout

11.1 Layout Guidelines

When using multiple bit logic devices inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Layout Example specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC}, whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver.

11.2 Layout Example

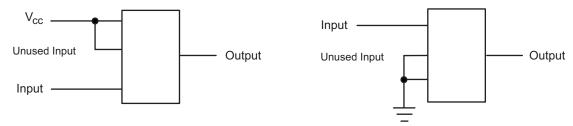


Figure 5. Layout Diagram



12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54LVC32A	Click here	Click here	Click here	Click here	Click here
SN74LVC32A	Click here	Click here	Click here	Click here	Click here

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com

22-Jul-2021

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9761801Q2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type -55 to 125		5962- 9761801Q2A SNJ54LVC 32AFK	Samples
5962-9761801QCA	ACTIVE	CDIP	J	J 14 1 Non-RoHS SNPB N / A for Pkg Type -55 to 125 & Green		-55 to 125	5962-9761801QC A SNJ54LVC32AJ	Samples			
5962-9761801QDA	ACTIVE	CFP	W	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9761801QD A SNJ54LVC32AW	Samples
SN74LVC32AD	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32A	Samples
SN74LVC32ADBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32ADBRG4	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32ADR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32A	Samples
SN74LVC32ADRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32A	Samples
SN74LVC32ADT	ACTIVE	SOIC	D	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32A	Samples
SN74LVC32ADTG4	ACTIVE	SOIC	D	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32A	Samples
SN74LVC32ANSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC32A	Samples
SN74LVC32APW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32APWE4	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32APWG4	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32APWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32APWRE4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32APWRG3	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples



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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74LVC32APWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32APWT	ACTIVE	TSSOP	PW	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC32A	Samples
SN74LVC32ARGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LC32A	Samples
SNJ54LVC32AFK	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9761801Q2A SNJ54LVC 32AFK	Samples
SNJ54LVC32AJ	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9761801QC A SNJ54LVC32AJ	Samples
SNJ54LVC32AW	ACTIVE	CFP	W	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9761801QD A SNJ54LVC32AW	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

PACKAGE OPTION ADDENDUM

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(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54LVC32A, SN74LVC32A:

Catalog: SN74LVC32A

Automotive: SN74LVC32A-Q1, SN74LVC32A-Q1

■ Enhanced Product : SN74LVC32A-EP, SN74LVC32A-EP

Military: SN54LVC32A

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

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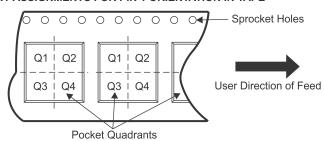
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

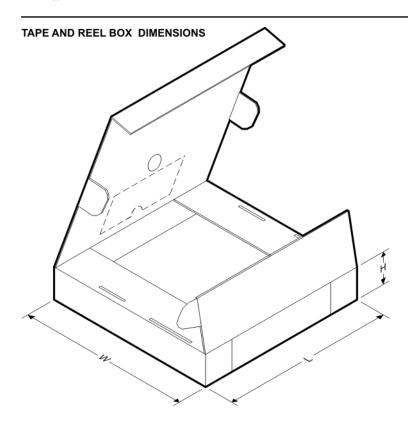


*All dimensions are nominal

All dimensions are nominal												1
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC32ADBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74LVC32ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC32ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC32ADT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC32ANSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74LVC32APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC32APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC32APWRG3	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC32APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC32APWT	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC32ARGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1



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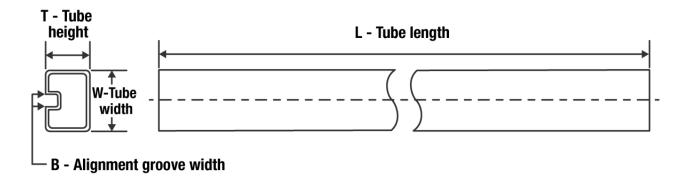
*All dimensions are nominal

All difficusions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC32ADBR	SSOP	DB	14	2000	853.0	449.0	35.0
SN74LVC32ADR	SOIC	D	14	2500	340.5	336.1	32.0
SN74LVC32ADR	SOIC	D	14	2500	853.0	449.0	35.0
SN74LVC32ADT	SOIC	D	14	250	210.0	185.0	35.0
SN74LVC32ANSR	SO	NS	14	2000	853.0	449.0	35.0
SN74LVC32APWR	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74LVC32APWR	TSSOP	PW	14	2000	853.0	449.0	35.0
SN74LVC32APWRG3	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74LVC32APWRG4	TSSOP	PW	14	2000	853.0	449.0	35.0
SN74LVC32APWT	TSSOP	PW	14	250	853.0	449.0	35.0
SN74LVC32ARGYR	VQFN	RGY	14	3000	853.0	449.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9761801Q2A	FK	LCCC	20	1	506.98	12.06	2030	NA
SN74LVC32AD	D	SOIC	14	50	506.6	8	3940	4.32
SN74LVC32APW	PW	TSSOP	14	90	530	10.2	3600	3.5
SN74LVC32APWE4	PW	TSSOP	14	90	530	10.2	3600	3.5
SN74LVC32APWG4	PW	TSSOP	14	90	530	10.2	3600	3.5
SNJ54LVC32AFK	FK	LCCC	20	1	506.98	12.06	2030	NA

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (S-PVQFN-N14)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206353-2/P 03/14

NOTE: All linear dimensions are in millimeters



RGY (S-PVQFN-N14)

PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
 Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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